SQJ174EP

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Automotive N-Channel 60 V (D-S) 175 °C MOSFET

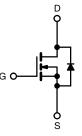


PRODUCT SUMMARY	
V _{DS} (V)	60
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0029
I _D (A)	293
Configuration	Single
Package	PowerPAK SO-8L

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C	; = 25 °C, unles	s otherwise noted	i)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	60	v	
Gate-source voltage		V _{GS}	± 20	v	
Continuous drain current	T _C = 25 °C ª	I-	293		
Continuous drain current	T _C = 125 °C	Ι _D	169		
Continuous source current (diode conduction) ^a		I _S	454	А	
Continuous source current (diode conduction) ^a Pulsed drain current ^b		I _{DM}	335		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	52		
Single pulse avalanche energy	L = 0.1 MH	E _{AS}	135	mJ	
Maximum newer discipation	T _C = 25 °C	Р	500	W	
Maximum power dissipation	T _C = 125 °C	P _D	166	vv	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	<u> </u>	
Soldering recommendations (peak temperature) ^d			260		

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^c	R _{thJA}	42	°C/W
Junction-to-case (drain)		R _{thJC}	0.30	0/10

Notes

a. Package limited

b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (<u>www.vishay.com/doc?73257</u>). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

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SPECIFICATIONS ($T_C = 25 \ ^{\circ}C$,	unless otherv	vise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = 250 μA	60	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$		3.0	3.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	= 0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 60 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA
		$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 175 °C	-	-	250	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	30	-	-	Α
		V _{GS} = 10 V	I _D = 15 A	-	0.00235	0.0029	
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 15 A, T _J = 125 °C	-	-	0.0049	Ω
		$V_{GS} = 10 V$	l _D = 15 A, T _J = 175 °C	-	-	0.0060	
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 10 A	-	23	-	S
Dynamic ^b							
Input capacitance	C _{iss}			-	4365	6111	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	1828	2560	pF
Reverse transfer capacitance	C _{rss}			-	53	75	
Total gate charge ^c	Qg			-	54	81	
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 30 \text{ V}, \text{ I}_{D} = 40 \text{ A}$	-	21	-	nC
Gate-drain charge ^c	Q _{gd}			-	4	-	
Gate resistance	Rg		f = 1 MHz	0.6	1.3	2.0	Ω
Turn-on delay time ^c	t _{d(on)}			-	17	26	
Rise time ^c	t _r	V _{DD} =	30 V, R _L = 0.75 Ω	-	5	9	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 40 A$,	$V_{GEN} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$	-	29	44	ns
Fall time ^c	t _f			-	4	8	
Source-Drain Diode Ratings and Char	acteristics ^b			•			
Pulsed current ^a	I _{SM}			-	-	335	Α
Forward voltage	V _{SD}	I _F =	15 A, V _{GS} = 0 V	-	-	1.1	V
Body diode reverse recovery time	t _{rr}			-	50	100	ns
Body diode reverse recovery charge	Q _{rr}		$\Lambda di/dt = 100 \Lambda/ma$	-	52	104	nC
Reverse recovery fall time	t _a	I _F = 8	A, di/dt = 100 A/µs	-	22	-	
Reverse recovery rise time	t _b	1		-	29	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	1.8	-	А

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

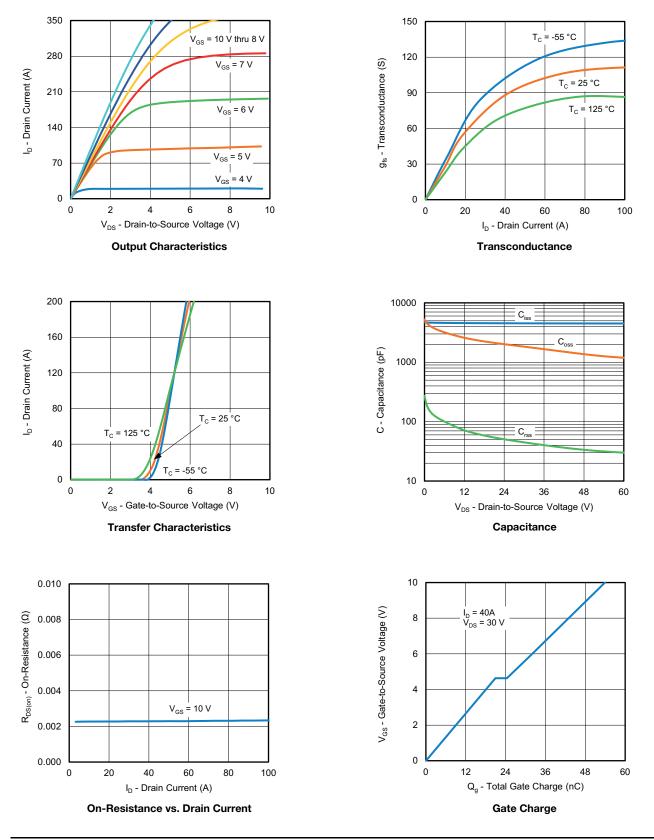
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



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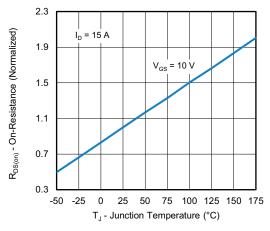
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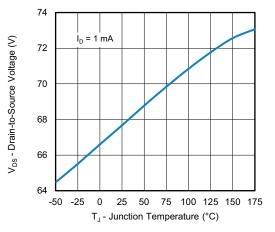
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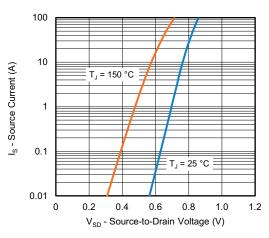
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



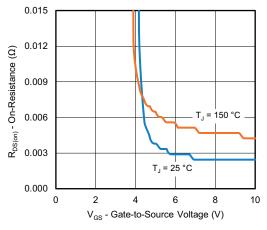
On-Resistance vs. Junction Temperature



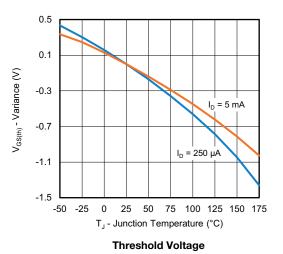
Drain Source Breakdown vs. Junction Temperature

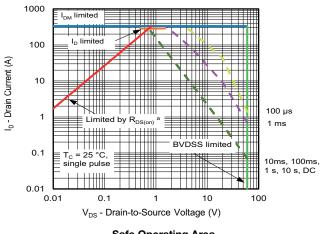


Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to Source Voltage





Safe Operating Area

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

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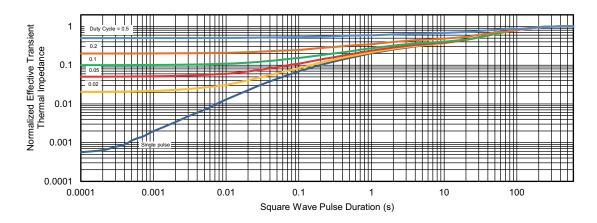
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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



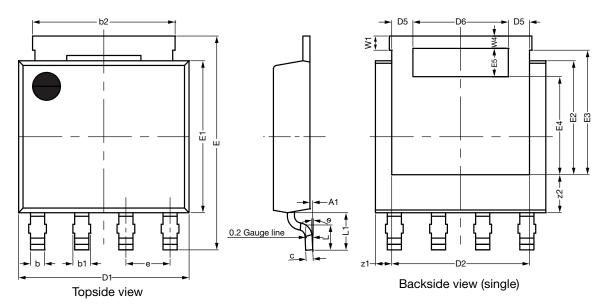
Normalized Thermal Transient Impedance, Junction-to-Ambient

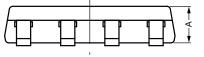
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PowerPAK[®] SO-8L (PPKSO8LWLA) Case Outline 3





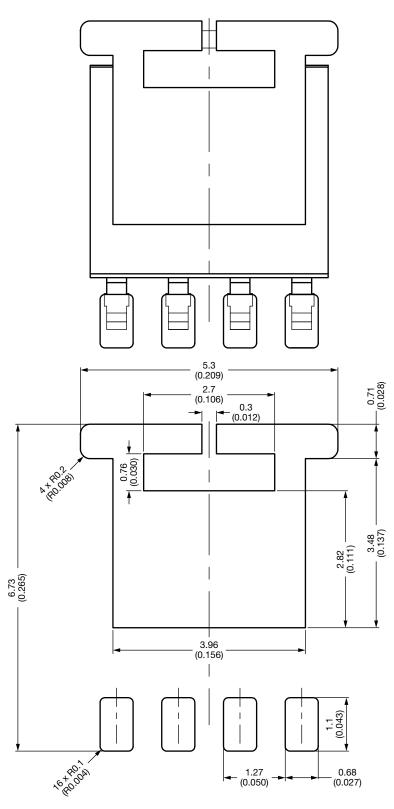
DIM.		MILLIMETERS		INCHES			
DIN.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.00	1.05	1.10	0.039	0.041	0.043	
A1	0.00		0.127	0.000		0.005	
b	0.33	0.41	0.49	0.013	0.016	0.019	
b1	0.43	0.51	0.59	0.017	0.020	0.023	
b2	4.00	4.10	4.20	0.157	0.161	0.165	
С	0.15	0.20	0.25	0.006	0.008	0.010	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D5	0.51	0.61	0.71	0.020	0.024	0.028	
D6	2.64	2.74	2.84	0.104	0.108	0.112	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	3.18	3.28	3.38	0.125	0.129	0.133	
E3	3.48	3.58	3.68	0.137	0.141	0.145	
E4	2.72	2.82	2.92	0.107	0.111	0.115	
E5	0.71	0.81	0.91	0.028	0.032	0.036	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
W1	0.31	0.41	0.51	0.012	0.016	0.020	
W4	0.31	0.36	0.41	0.012	0.014	0.016	
z1	0.37	0.47	0.57	0.015	0.019	0.022	
z2	0.99	1.09	1.19	0.039	0.043	0.047	
θ	0°		5°	0°		5°	

Note

• Millimeter will govern



Recommended Land Pattern PowerPAK® SO-8L Single Short Ear



Dimensions in Millimeters (Inches)

Revision: 24-Aug-2021

Document Number: 78020



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